



# ACE13402M

## N-Channel 30-V (D-S) MOSFET

### Features

- Low  $r_{DS(on)}$  trench technology
- Low thermal impedance
- Fast switching speed

PRODUCT SUMMARY		
$V_{DS}$ (V)	$r_{DS(on)}$ (m $\Omega$ )	$I_D$ (A)
30	27 @ $V_{GS} = 10V$	7.1
	35 @ $V_{GS} = 4.5V$	6.2

### Applications

- DC/DC Conversion
- Power Routing
- Motor Drives

### Absolute Maximum Ratings

Parameter	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>a</sup>	$I_D$	$T_A=25^\circ C$	7.1
		$T_A=70^\circ C$	5.7
Pulse Drain Current <sup>b</sup>	$I_{DM}$	30	A
Continuous Drain Current (Diode Continuous) <sup>a</sup>	$I_S$	2.9	A
Power Dissipation <sup>a</sup>	$P_D$	$T_A=25^\circ C$	2
		$T_A=70^\circ C$	1.3
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	$^\circ C$

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	$t \leq 10\text{sec}$	62.5
		Steady State	110

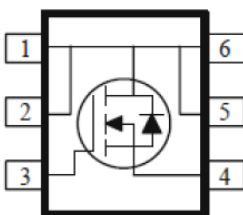
Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

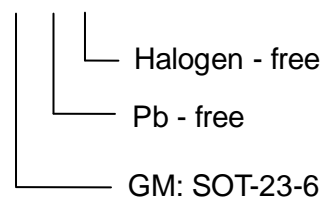
### Packaging Type

SOT-23-6



### Ordering information

ACE13402M XX + H





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### Electrical Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Source Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1			V
Gate Body Leakage	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=24V, V_{GS}=0V$			1	uA
		$V_{DS}=24V, V_{GS}=0V, T_J=55^\circ C$			25	
On-State Drain-Current <sup>a</sup>	$I_{D(on)}$	$V_{DS}=5V, V_{GS}=10V$	12			A
Static Drain-Source On-Resistance <sup>a</sup>	$r_{DS(ON)}$	$V_{GS}=10V, I_D=5.6A$			27	mΩ
		$V_{GS}=4.5V, I_D=4.5A$			35	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS}=15V, I_D=5.6A$		11		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S=1.5A, V_{GS}=0V$		0.79		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS}=15V, V_{GS}=4.5V,$ $I_D=5.6A$		4.1		nC
Gate-Source Charge	$Q_{gs}$			1.0		
Gate-Drain Charge	$Q_{gd}$			2.1		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=15V, R_L=2.7\Omega$ $I_D=5.6A, V_{GEN}=10V$ $R_{GEN}=6\Omega,$		2		ns
Rise Time	$t_r$			4		
Turn-Off Delay Time	$t_{d(off)}$			16		
Fall Time	$t_f$			4		
Input Capacitance	$C_{iss}$	$V_{DS}=15V, V_{GS}=0V$ $f=1MHz$		360		pF
Output Capacitance	$C_{oss}$			55		
Reverse Transfer Capacitance	$C_{rss}$			46		

Note:

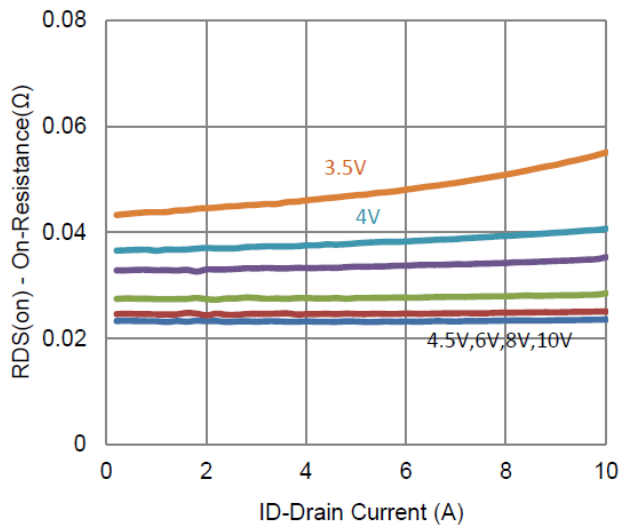
- a. Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.



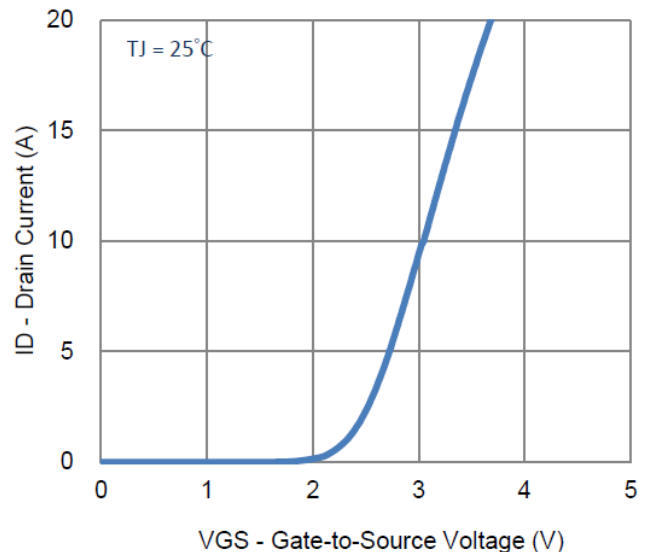
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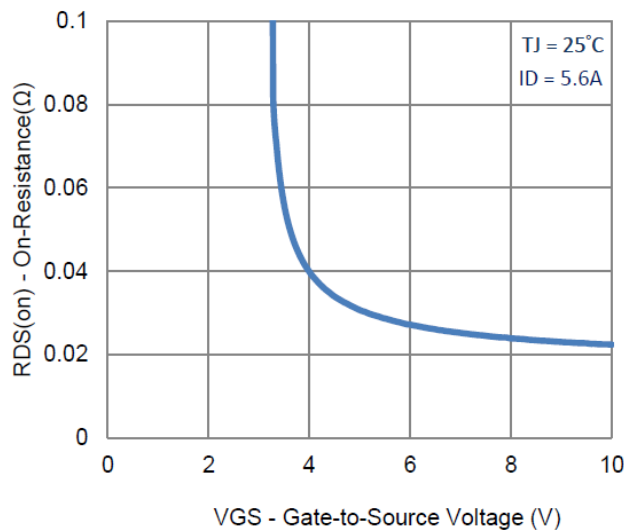
### Typical Electrical Characteristics



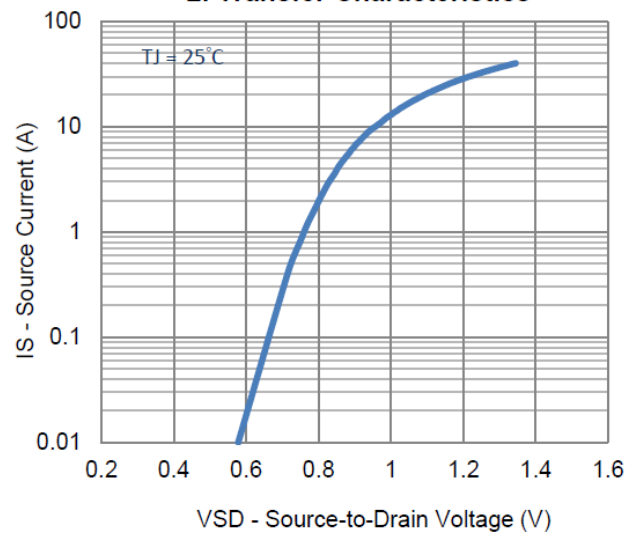
1. On-Resistance vs. Drain Current



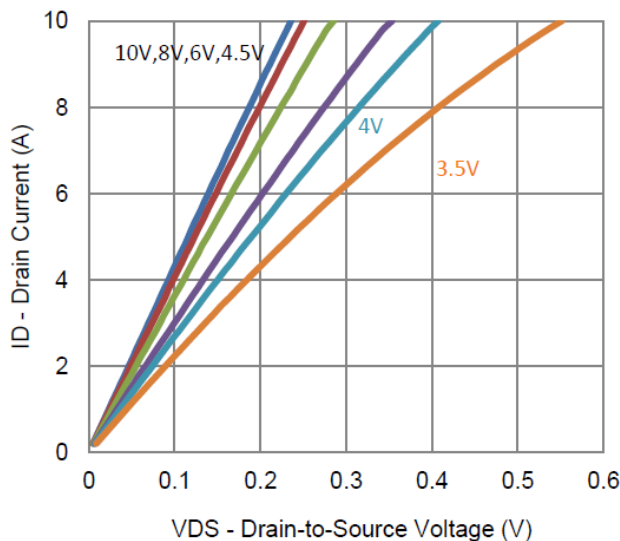
2. Transfer Characteristics



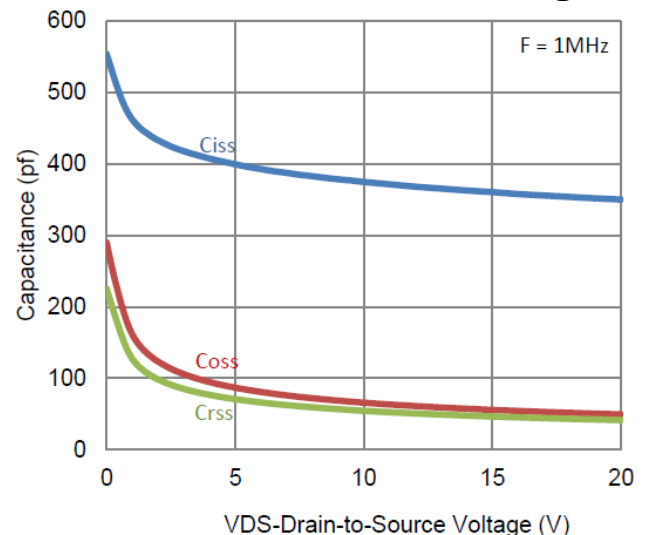
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage



5. Output Characteristics

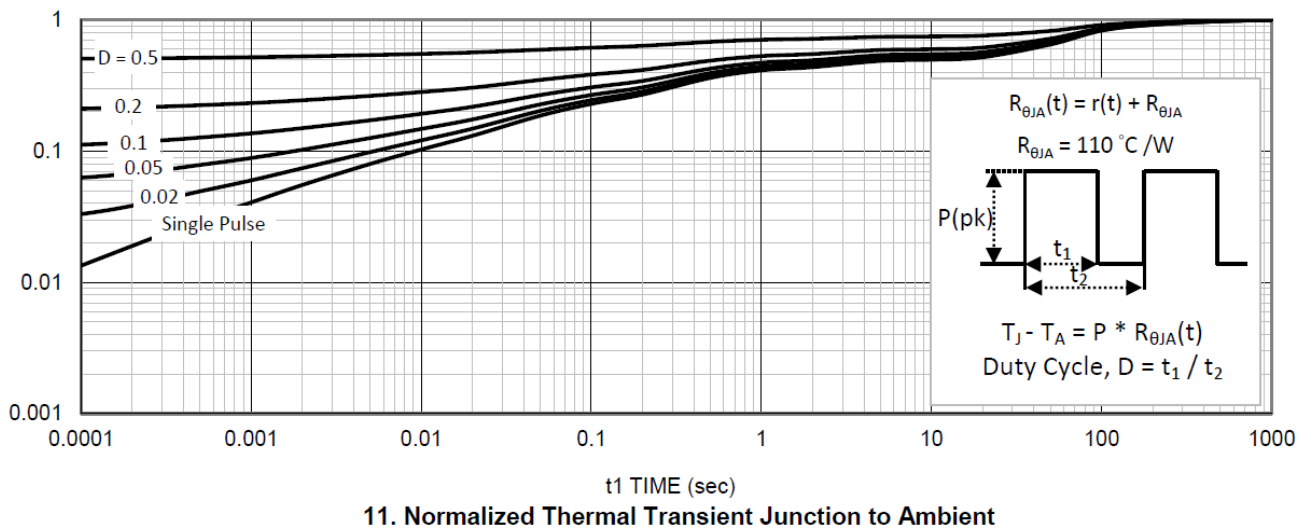
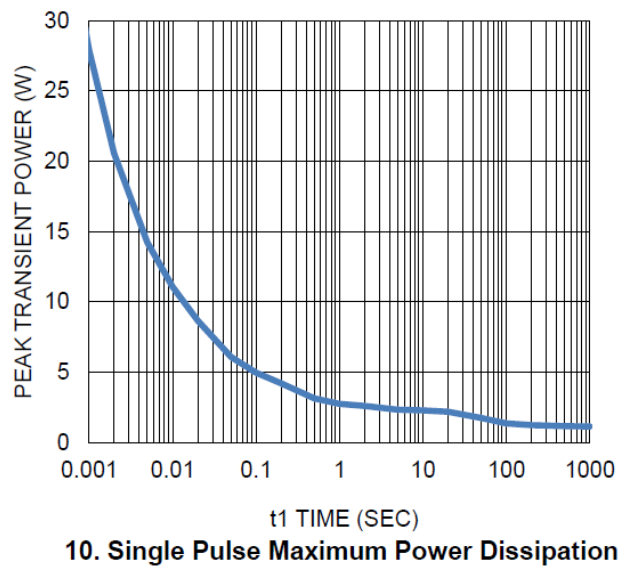
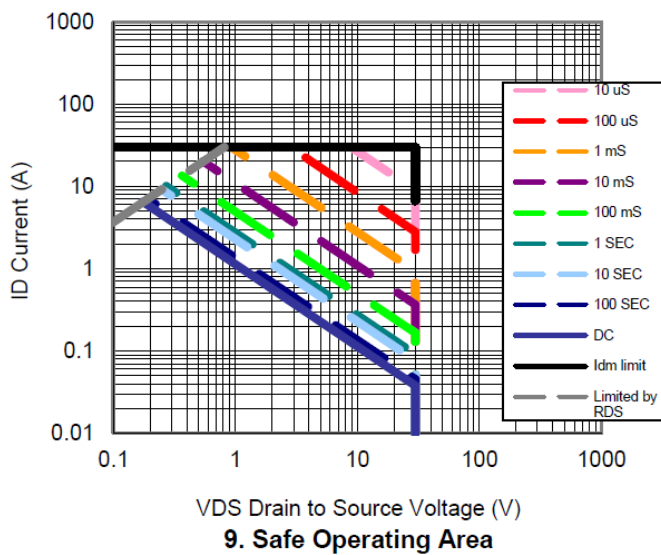
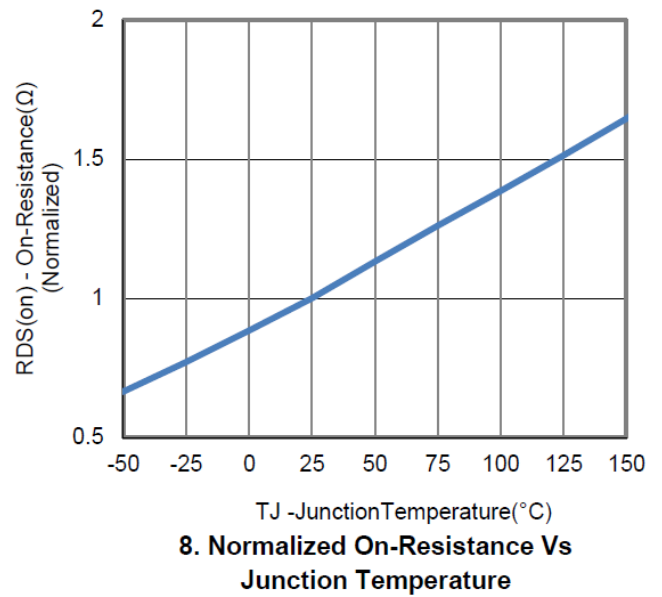
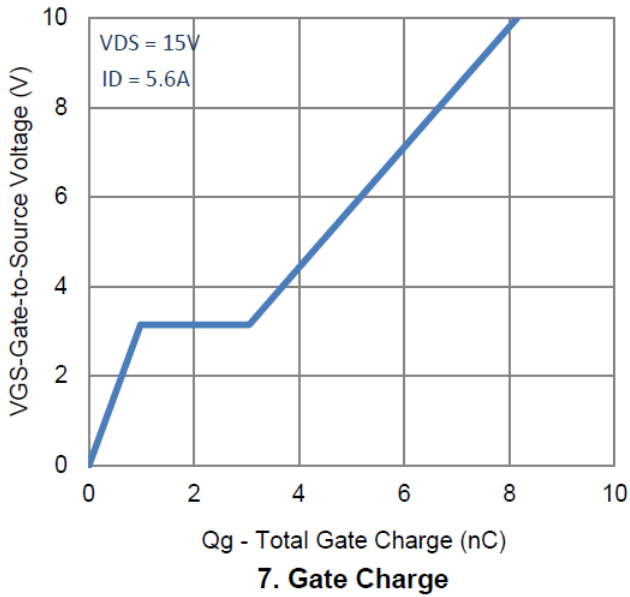


6. Capacitance



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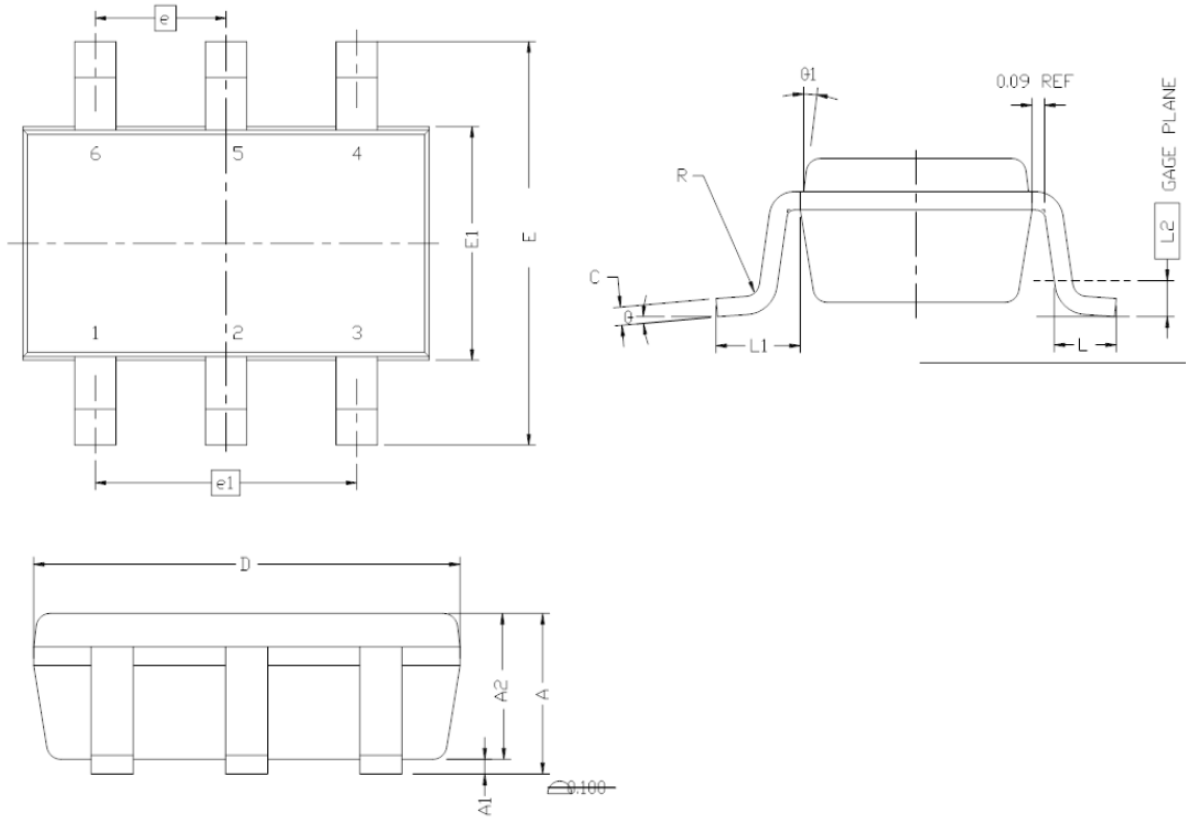


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### Packing Information

#### SOT-23-6



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	0.935		1.10
A1	0.01		0.10
A2	0.70		1.00
b	0.25	0.32	0.40
C	0.10	0.15	0.20
D	2.95	3.05	3.10
E	2.70	2.85	2.98
E1	1.55	1.65	1.70
e	0.95 BSC		
L	0.30		0.60
L1	0.60 REF		
L2	0.25 BSC		
R	0.10		
$\theta$	0°	4°	8°
$\theta1$	7° NOM		



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### Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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